

Schottky Diode

V_{RRM} = 200 V
 I_{FAV} = 2x 30 A
 V_F = 0,7 V

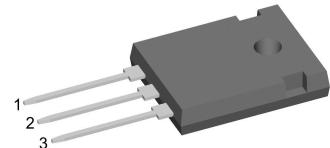
High Performance Schottky Diode

Low Loss and Soft Recovery

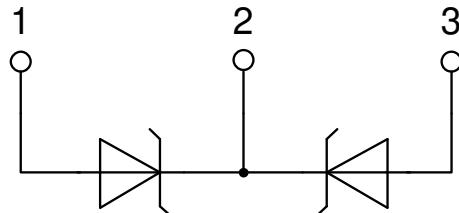
Common Cathode

Part number

DSSK60-02A



Backside: cathode



Features / Advantages:

- Very low V_F
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

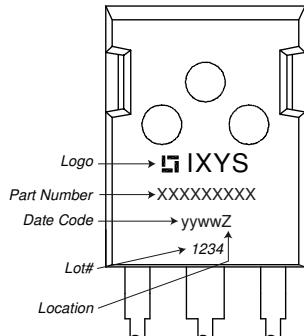
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Schottky

| Symbol | Definition | Conditions | Ratings | | | |
|-------------------|--|--|---|------|------------------------------|---------|
| | | | min. | typ. | max. | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^\circ C$ | | | 200 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^\circ C$ | | | 200 | V |
| I_R | reverse current, drain current | $V_R = 200 V$ $V_R = 200 V$ | $T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$ | | 2 5 | mA |
| V_F | forward voltage drop | $I_F = 30 A$ $I_F = 60 A$ $I_F = 30 A$ $I_F = 60 A$ | $T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$ | | 0,83 0,98 0,70 0,88 | V |
| I_{FAV} | average forward current | $T_C = 140^\circ C$ rectangular $d = 0.5$ | $T_{VJ} = 175^\circ C$ | | 30 | A |
| V_{F0} r_F | threshold voltage slope resistance } for power loss calculation only | | $T_{VJ} = 175^\circ C$ | | 0,47 5,8 | V mΩ |
| R_{thJC} | thermal resistance junction to case | | | | 0,5 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | 0,25 | | K/W |
| P_{tot} | total power dissipation | | $T_C = 25^\circ C$ | | 300 | W |
| I_{FSM} | max. forward surge current | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 V$ | $T_{VJ} = 45^\circ C$ | | 700 | A |
| C_J | junction capacitance | $V_R = 24 V$ f = 1 MHz | $T_{VJ} = 25^\circ C$ | 394 | | pF |

Package TO-247

| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
|---------------|------------------------------|----------------------------|------|------|------|------|
| I_{RMS} | RMS current | per terminal ¹⁾ | | | 70 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 175 | °C |
| T_{op} | operation temperature | | -55 | | 150 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 6 | | g |
| M_d | mounting torque | | 0,8 | | 1,2 | Nm |
| F_c | mounting force with clip | | 20 | | 120 | N |

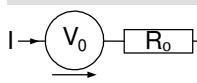
Product Marking


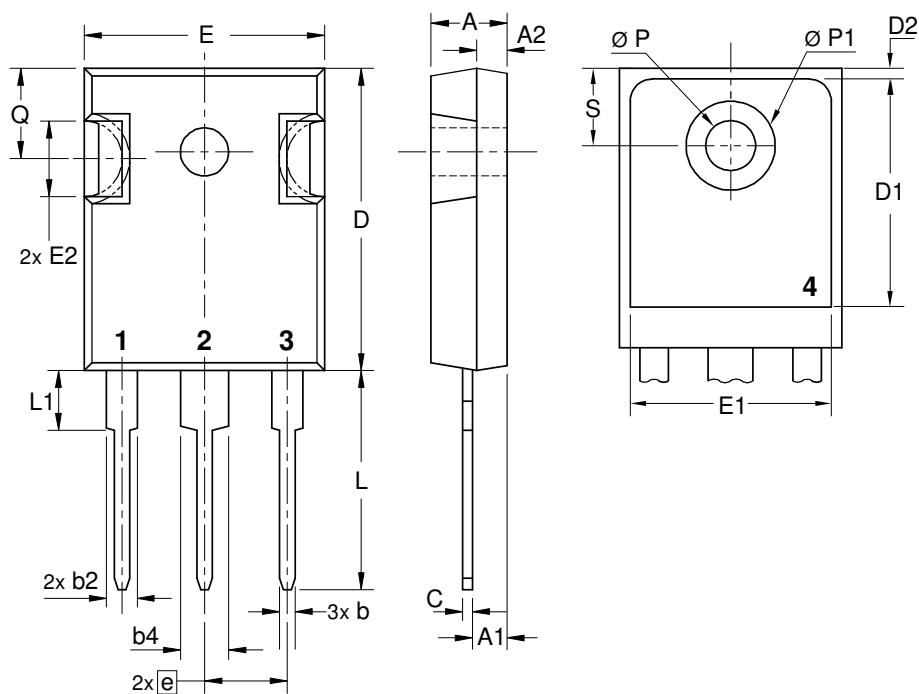
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSSK60-02A | DSSK60-02A | Tube | 30 | 500315 |

| Similar Part | Package | Voltage class |
|--------------|----------------|---------------|
| DSSK60-02AR | ISOPLUS247 (3) | 200 |
| DSA90C200HR | ISO247 (3) | 200 |

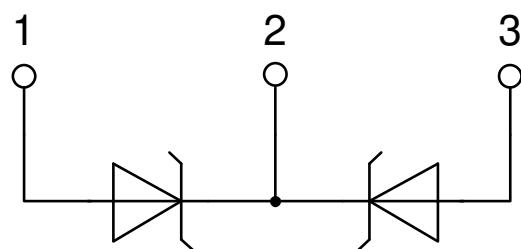
Equivalent Circuits for Simulation
^{*}on die level

 $T_{VJ} = 175^\circ\text{C}$

| | | |
|---|--------------------|--------|
|  | Schottky | |
| $V_{0\ max}$ | threshold voltage | 0,47 V |
| $R_{0\ max}$ | slope resistance * | 3,3 mΩ |

Outlines TO-247


| Sym. | Inches min. max. | Millimeter min. max. |
|------|------------------------|----------------------------|
| A | 0.185 0.209 | 4.70 5.30 |
| A1 | 0.087 0.102 | 2.21 2.59 |
| A2 | 0.059 0.098 | 1.50 2.49 |
| D | 0.819 0.845 | 20.79 21.45 |
| E | 0.610 0.640 | 15.48 16.24 |
| E2 | 0.170 0.216 | 4.31 5.48 |
| e | 0.215 BSC | 5.46 BSC |
| L | 0.780 0.800 | 19.80 20.30 |
| L1 | - 0.177 | - 4.49 |
| Ø P | 0.140 0.144 | 3.55 3.65 |
| Q | 0.212 0.244 | 5.38 6.19 |
| S | 0.242 BSC | 6.14 BSC |
| b | 0.039 0.055 | 0.99 1.40 |
| b2 | 0.065 0.094 | 1.65 2.39 |
| b4 | 0.102 0.135 | 2.59 3.43 |
| c | 0.015 0.035 | 0.38 0.89 |
| D1 | 0.515 - | 13.07 - |
| D2 | 0.020 0.053 | 0.51 1.35 |
| E1 | 0.530 - | 13.45 - |
| Ø P1 | - 0.29 | - 7.39 |



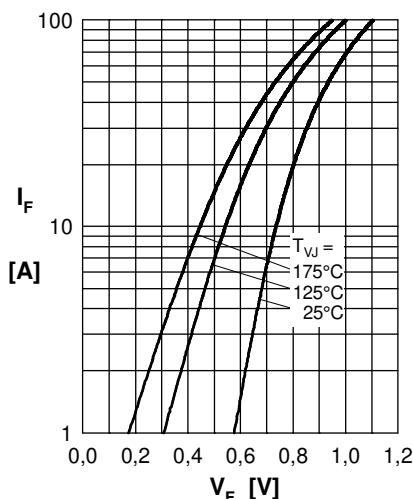
Schottky


Fig. 1 Max. forward voltage drop characteristics

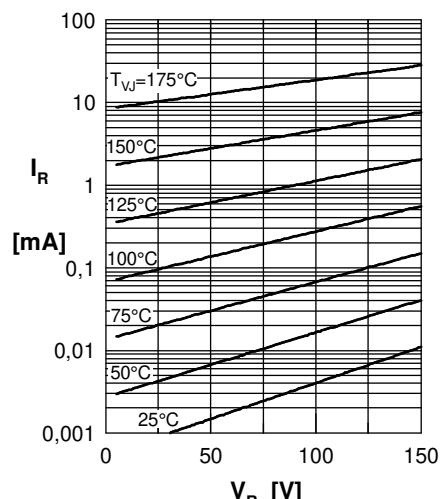


Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

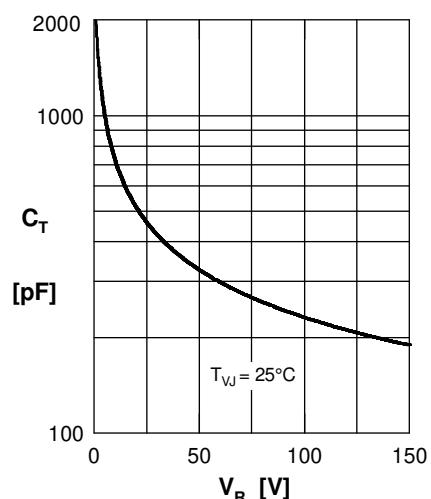


Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

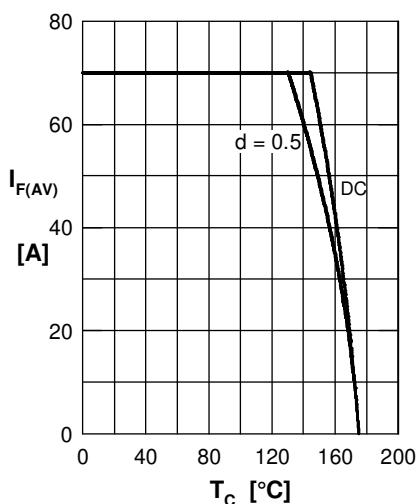


Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp. T_C

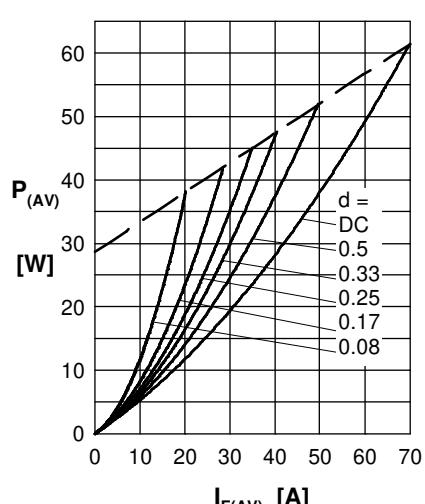
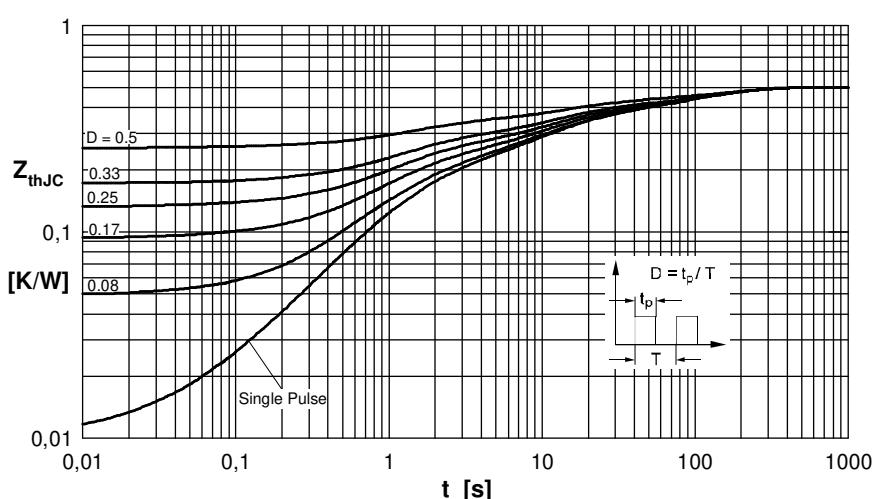


Fig. 5 Forward power loss characteristics



Note: All curves are per diode

Fig. 6 Transient thermal impedance junction to case at various duty cycles